

10V Drive Nch MOSFET

R6025ANZ

●Structure

Silicon N-channel MOSFET

● Features

- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Gate-source voltage (VGSS) guaranteed to be ±30V.
- 4) Drive circuits can be simple.
- 5) Parallel use is easy.

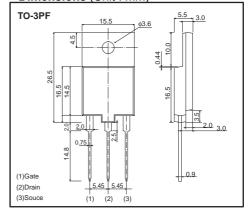
Applications

Switching

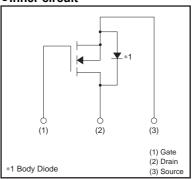
Packaging specifications

Туре	Package	Tube	
	Basic ordering unit (pieces)	360	
R6025ANZ		0	

●Dimensions (Unit:mm)



●Inner circuit



●Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		VDSS	600	V
Gate-source voltage		Vgss	±30	V
Drain current	Continuous	lo *;	±25	А
Drain current	Pulsed	I _{DP} *	±100	А
Source current (Body Diode)	Continuous	ls *	25	А
	Pulsed	Isp *	100	А
Avalanche current		las *	12.5	А
Avalanche energy		Eas *	39.0	mJ
Total power dissipation (Tc=25°C)		Po	150	W
Channel temperature	Tch	150	°C	
Range of storage tem	Tstg	-55 to +150	°C	

Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to case	Rth(ch-c)	0.83	°C/W

^{*1} Pw≤10 μ s, Duty cycle≤1% *2 L \leftrightarrows 500 μ H, VbD=50V, Rg=25 Ω , Starting, Tch=25°C

^{*3} Limited only by maximum temperature allowed.

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Gate-source leakage	Igss	-	_	±100	nA	Vgs=±30V, Vps=0V	
Drain-source breakdown voltage	V(BR)DSS	600	_	_	V	In=1mA, Vgs=0V	
Zero gate voltage drain current	IDSS	_	_	100	μΑ	VDS=600V, VGS=0V	
Gate threshold voltage	VGS(th)	2.5	_	4.5	V	Vps=10V, lp=1mA	
Static drain-source on-state resistance	RDS(on)*	_	0.12	0.15	Ω	In=12.5A, Vgs=10V	
Forward transfer admittance	Yfs *	14	20	-	S	Vps=10V, lp=12.5A	
Input capacitance	Ciss	_	3250	_	pF	Vps=25V	
Output capacitance	Coss	-	2400	_	pF	Vgs=0V	
Reverse transfer capacitance	Crss	_	85	-	pF	f=1MHz	
Turn-on delay time	td(on) *	_	50	-	ns	VDD≒300V, ID=12.5A	
Rise time	tr *	_	135	-	ns	Vgs=10V	
Turn-off delay time	td(off) *	_	185	-	ns	RL=24Ω	
Fall time	t _f *	_	110	_	ns	R _G =10Ω	
Total gate charge	Qg *	-	88	_	nC	V _{DD} ≒300V	
Gate-source charge	Qgs *	-	25	_	nC	I _D =25A V _G s=10V	
Gate-drain charge	Qgd *	-	30	_	nC	R _L =12Ω / R _G =10Ω	

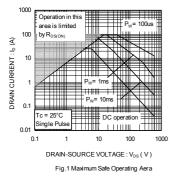
^{*} Pulsed

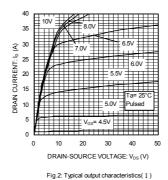
●Body diode characteristics (Source-drain) (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	Vsp*	_	_	1.5	V	I _S = 12.5A, V _{GS} =0V

^{*} Pulsed

•Electrical characteristic curves





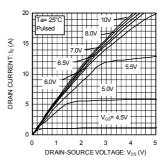
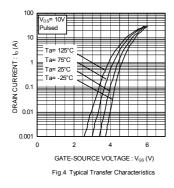
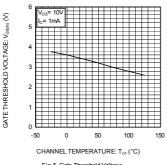


Fig.3: Typical output characteristics(II)





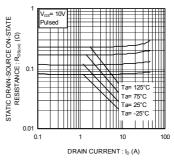


Fig.5 Gate Threshold Voltage vs. Channel Temperature

Fig.6 Static Drain-Source On-State Resistance vs. Drain Current

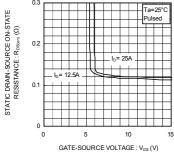


Fig.7 Static Drain-Source On-State
Resistance vs. Gate Source Voltage

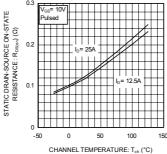
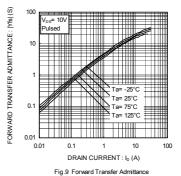
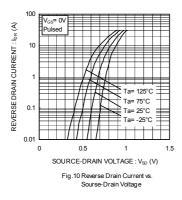
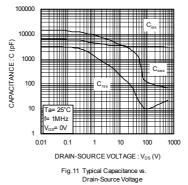


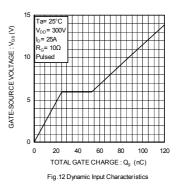
Fig.8 Static Drain-Source On-State Resistance vs. Channel Temperature

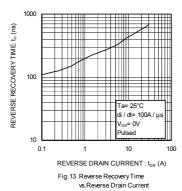


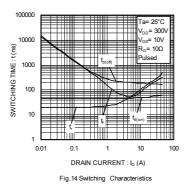
vs. Drain Current











•Switching characteristics measurement circuit

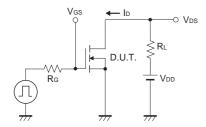


Fig.1-1 Switching Time Measurement Circuit

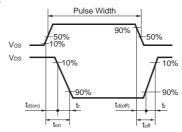


Fig.1-2 Switching Waveforms

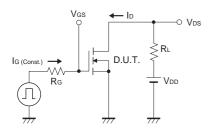


Fig.2-1 Gate Charge Measurement Circuit

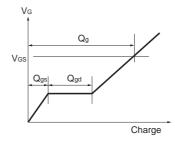


Fig.2-2 Gate Charge Waveform

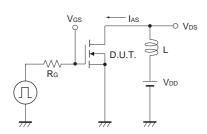


Fig.3-1 Avalanche Measurement circuit

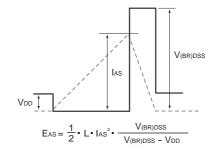


Fig.3-2 Avalanche waveform

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